# VS-1ENH01-M3, VS-1ENH02-M3

Vishay Semiconductors



# Ultrafast Rectifier, 1 A FRED Pt®



Cathode O Anode

### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
V <sub>R</sub>	100 V, 200 V			
V <sub>F</sub> at I <sub>F</sub>	0.69 V			
I <sub>FSM</sub>	40 A			
t <sub>rr</sub> (typ.)	23 ns			
T <sub>J</sub> max.	175 °C			
Package	SMP (DO-220AA)			
Circuit configuration	Single			

### FEATURES

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATION**

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial and automotive applications.

### **MECHANICAL DATA**

Case: SMP (DO-220AA)

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002, meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse	VS-1ENH01-M3	M		100	V
voltage	VS-1ENH02-M3	V <sub>RRM</sub>		200	v
Average rectified forward current		I <sub>F(AV)</sub>	T <sub>C</sub> = 168 °C	1	^
Non-repetitive peak surge	e current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, 10 ms sine pulse	40	A
Operating junction and st	orage temperatures	TJ, T <sub>Stg</sub>		-55 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage,	VS-1ENH01-M3	V <sub>BR</sub> ,	100.04	100	-	-	
blocking voltage	VS-1ENH02-M3	V <sub>R</sub>	I <sub>R</sub> = 100 μΑ	200	-	-	V
Forward voltage		VF	I <sub>F</sub> = 1 A	-	0.86	0.92	v
T Orward Voltage		۷F	I <sub>F</sub> = 1 A, T <sub>J</sub> = 150 °C	-	0.69	0.74	
Reverse leakage current		$I_R = \frac{V_R = V_R \text{ rated}}{T_J = 150 \text{ °C}, V_R = V_R \text{ rated}}$	$V_{R} = V_{R}$ rated	-	-	2	
			-	-	20	μA	
Junction capacitance		CT	V <sub>R</sub> = 200 V	-	8	-	pF

Document Number: 96578

RoHS



For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



# **Vishay Semiconductors**

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	23	-	-
Reverse recovery time	t <sub>rr</sub>	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	28	
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 1 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 100 V	-	14	-	A nC
		T <sub>J</sub> = 125 °C		-	22	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	1.7	-	
		T <sub>J</sub> = 125 °C		-	2.7	-	
	0	T <sub>J</sub> = 25 °C		-	10	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	29	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction mount		R <sub>thJM</sub> <sup>(1)</sup>	Infinite heatsink	-	7	9	°C/W
Thermal resistance, junction to ambient		R <sub>thJA</sub>	PCB footprint 4.8 mm x 4.8 mm	-	107	-	C/W
VS-1ENH01-M3			Case style SMP (DO-220AA)	1H1			
Marking device	VS-1ENH02-M3		Case signe SiviP (DO-220AA)		1H2		

### Note

<sup>(1)</sup> Thermal resistance junction to mount follows JEDEC<sup>®</sup> 51-14 transient dual interface test method (TDIM)

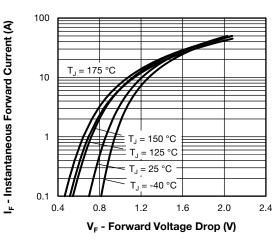


Fig. 1 - Typical Forward Voltage Drop Characteristics

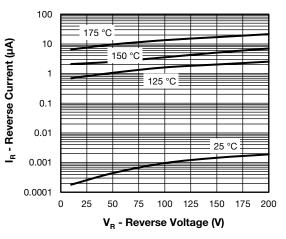


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



**Vishay Semiconductors** 

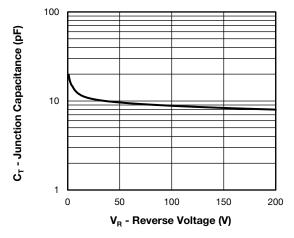


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

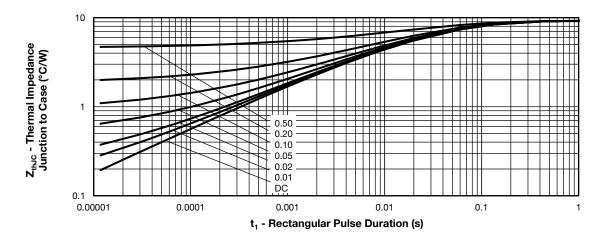
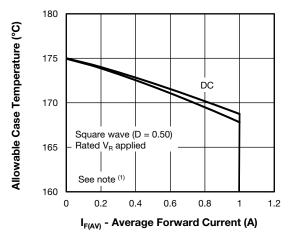
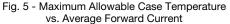


Fig. 4 - Transient Thermal Impedance, Junction to Case



www.vishay.com



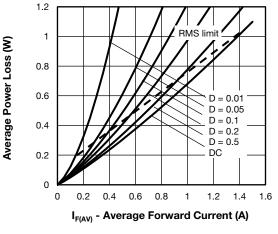


Fig. 6 - Forward Power Loss Characteristics

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = I_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 5);} \\ \mbox{Pd}_{REV} = \mbox{inverse power loss} = V_{R1} \times I_{R} \mbox{ (1 D);} \mbox{ I}_{R} \mbox{ at } V_{R1} = \mbox{rated } V_{R} \end{array}$

Revision: 28-Jan-2021

3

Document Number: 96578

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

# VS-1ENH01-M3, VS-1ENH02-M3

**Vishay Semiconductors** 

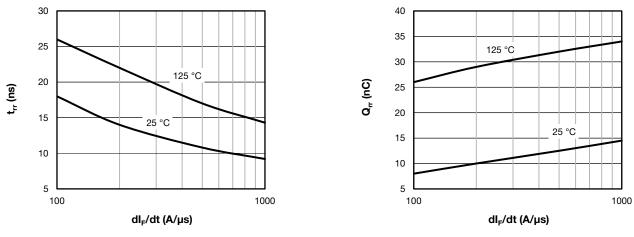


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

www.vishay.com

SHAY



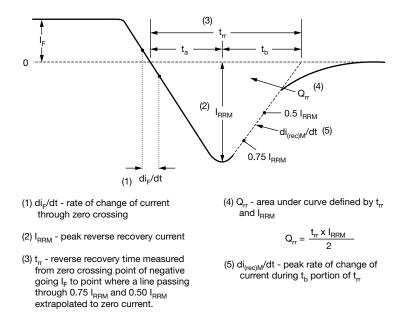


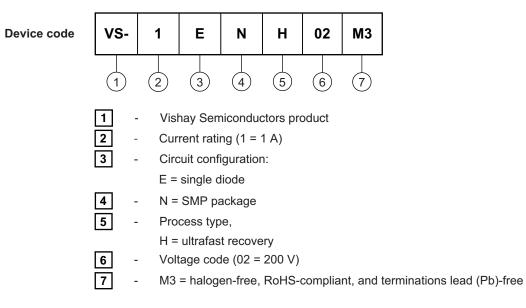
Fig. 9 - Reverse Recovery Waveform and Definitions



# VS-1ENH01-M3, VS-1ENH02-M3

## **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-1ENH01-M3/84A	84A	3000	7" diameter plastic tape and reel			
VS-1ENH01-M3/85A	85A	10 000	13" diameter plastic tape and reel			
VS-1ENH02-M3/84A	84A	3000	7" diameter plastic tape and reel			
VS-1ENH02-M3/85A	85A	10 000	13" diameter plastic tape and reel			

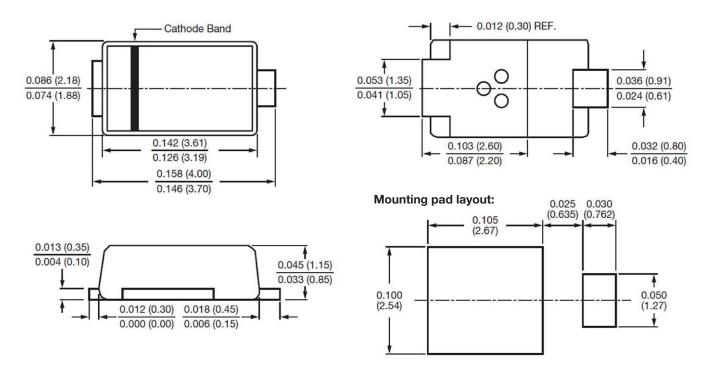
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96547				
Part marking information	www.vishay.com/doc?96574			
Packaging information	www.vishay.com/doc?88869			
SPICE model	www.vishay.com/doc?96550			



**Vishay Semiconductors** 

# SMP (DO-220AA)

## **DIMENSIONS** in inches (millimeters)





Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.